

G1V(A)10C

SIDACs / Uni-directional (G1V Series)

90V, 80A

Feature

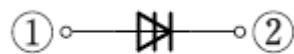
- Uni-directional
- Miniaturized compared to a K1V series
- For pulse generation, DC power with switching operation
- A reliable product with a track record, developed for many applications
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): AX06



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tl=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-40 to 125	°C
Junction temperature	Tj		125	°C
Maximum off-state voltage	V _{DRM(A)}		90	V
RMS on-state current	I _T	Tl=98°C, 50Hz sine wave, θ=180°	1	A
Pulse on-state current	I _{TRM}	Ta=25°C, pulse width 10μs, 60Hz sine wave	80	A
Critical rate of rise of on-state current	di _T /dt		80	A/μs

* : See the original Specifications

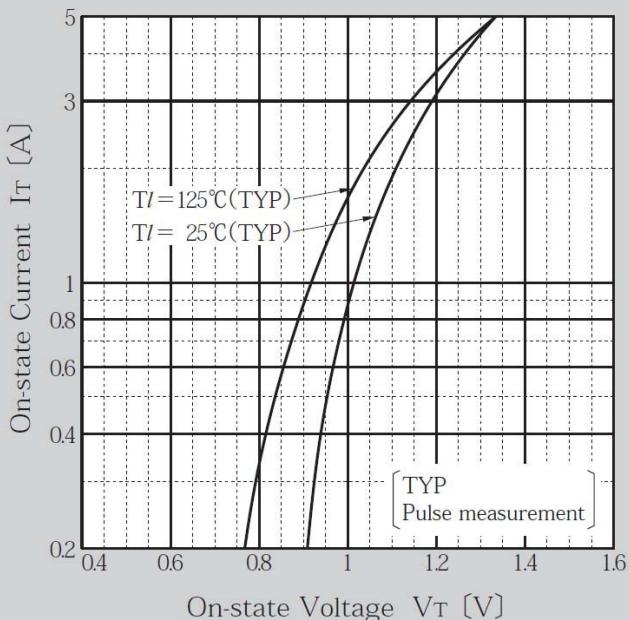
Electrical Characteristics (unless otherwise specified : T_l=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Breakover voltage	V _{BO(A)}	Pulse measurement, dv/dt=4V/ms	95		110	V
Off-state current	I _{DRM(A)}	VD=90V			10	µA
Breakover current	I _{BO(A)}				0.5	mA
Holding current	I _{H(A)}				60	mA
Holding current	I _{H(K)}				60	mA
On-state voltage	V _{T(A)}	IT=1A			1.5	V
On-state voltage	V _{T(K)}	IT=1A			1.5	V
Switching resistance	R _{S(A)}		0.1			kΩ
Thermal resistance	R _{th(j-l)}	Junction to lead			20	°C/W

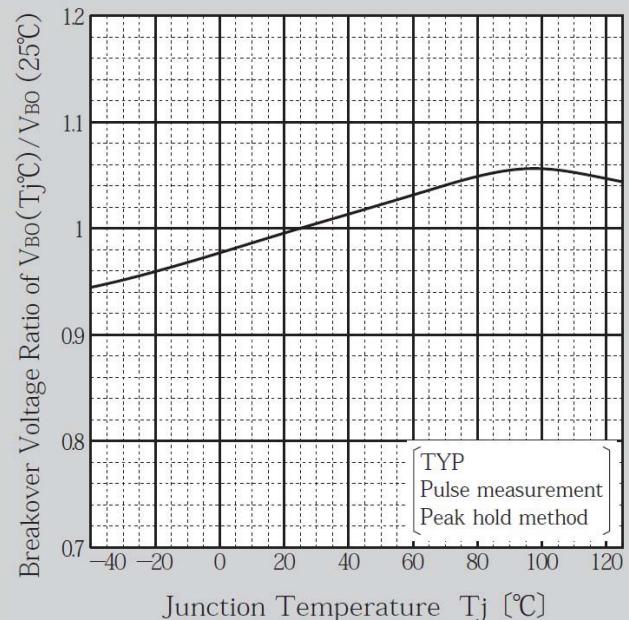
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CHARACTERISTIC DIAGRAMS

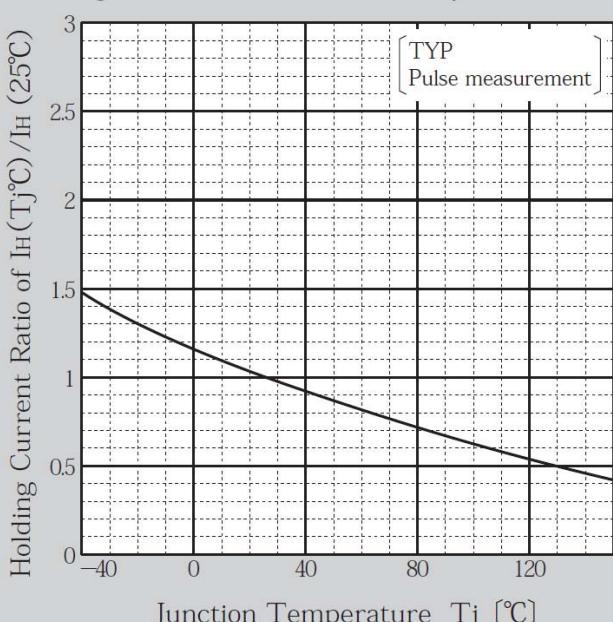
On-state Voltage vs On-state Current



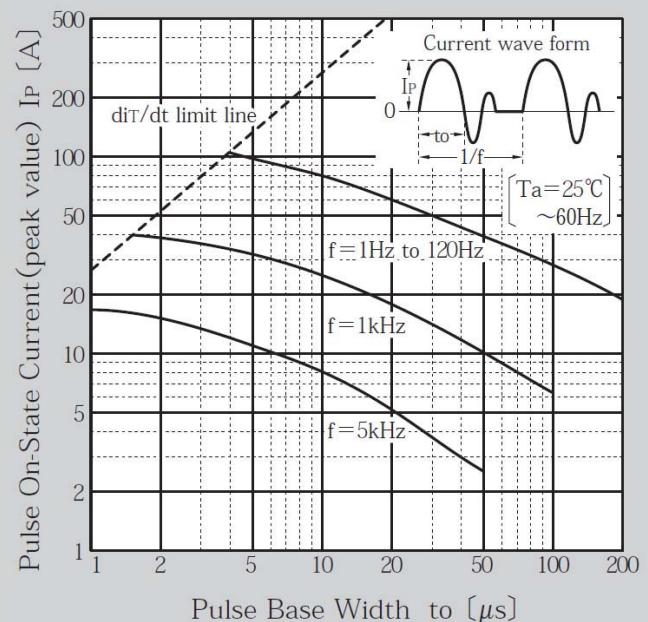
Breakover Voltage vs Junction Temperature

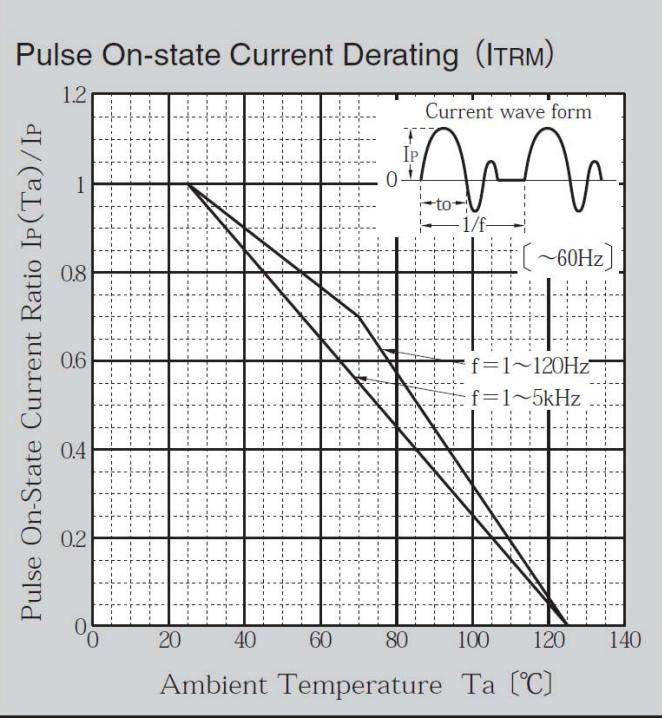


Holding Current vs Junction Temperature



Pulse On-state Current Rating (I_{TRM})





Outline Dimensions

unit:mm

scale: 2/1

A2

JEDEC Code	—
JEITA Code	—
House Name	AX06

